











LMV321, LMV324, LMV358

SLOS263X -AUGUST 1999-REVISED MAY 2020

LMV3xx Low-Voltage Rail-to-Rail Output Operational Amplifier

Features

- For an upgraded version refer to LMV321A, LMV324A, and LMV358A
- 2.7-V and 5-V performance
- -40°C to +125°C operation
- No crossover distortion
- Low supply current
 - LMV321: 130 μA (typical)
 - LMV358: 210 μA (typical)
 - LMV324: 410 μA (typical)
- Rail-to-rail output swing
- ESD protection exceeds JESD 22
 - 2000-V human-body model
 - 1000-V charged-device model

2 Applications

- **Desktop PCs**
- HVAC: heating, ventilating, and air conditioning
- Motor control: AC induction
- Netbooks
- Portable media players
- Power: telecom DC/DC module: digital
- Professional audio mixers
- Refrigerators
- Washing machines: high-end and low-end

3 Description

For an upgraded version with enhanced performance, please refer to LMV321A, LMV324A, and LMV358A.

The LMV321, LMV358, and LMV324 devices are single, dual, and quad low-voltage (2.7 V to 5.5 V) operational amplifiers with rail-to-rail output swing. These devices are the most cost-effective solutions for applications where low-voltage operation, space saving, and low cost are needed. These amplifiers are designed specifically for low-voltage (2.7 V to 5 V) operation, with performance specifications meeting or exceeding the LM358 and LM324 devices that operate from 5 V to 30 V. With package sizes down to one-half the size of the DBV (SOT-23) package, these devices can be used for a variety of applications.

Device Information⁽¹⁾

PART NUMBER	PACKAGE (PIN)	BODY SIZE		
LMV321	SOT-23 (5)	2.90 mm × 1.60 mm		
LIVI V 32 I	SC-70 (5)	2.00 mm × 1.25 mm		
	SOIC (8)	4.90 mm × 3.90 mm		
LAAV/250	VSSOP (8)	2.30 mm × 2.00 mm		
LMV358	VSSOP (8)	3.00 mm × 4.40 mm		
	TSSOP (8)	3.00 mm × 3.00 mm		
LM\/204	SOIC (14)	8.65 mm × 3.91 mm		
LMV324	TSSOP (14)	5.00 mm × 4.40 mm		

(1) For all available packages, see the orderable addendum at the end of the data sheet.

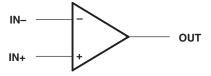




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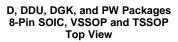
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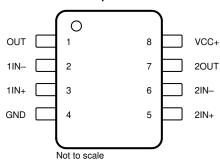
4 Revision History

Cł	nanges from Revision W (October 2014) to Revision X	Page
•	Deleted LMV324S mentions on the front page of the data sheet	1
•	Added end equipment links in Application section	1
•	Added recommended device notice for LMV321A, LMV358A, and LMV324A	1
•	Changed Device Information table to sort devices by channel count in ascending order	1
•	Changed Pin Configuration and Functions section by dividing the Pin Functions table into separate tables per device	e 3
•	Deleted LMV324S pinout information	4
•	Changed HBM ESD voltage from 2500 V to 2000 V	5
•	Changed CDM ESD voltage from 1500 V to 1000 V	5
•	Deleted Shutdown voltage threshold for LMV324S	5
•	Changed Thermal Information section by dividing the Thermal Information table into separate tables per device	<u>5</u>
•	Changed Thermal Information for LMV321	<u>5</u>
•	Deleted LMV324S Thermal Information	5
•	Changed Thermal Information for LMV324	<u>5</u>
•	Changed Thermal Information for LMV358	6
•	Deleted LMV324S test condition for supply current	<mark>7</mark>
•	Changed output short-circuit current for sourcing from 60 mA to 40 mA	8
•	Changed output short-circuit current for sinking from 160 mA to 40 mA	8
•	Deleted LMV324S test condition for supply current	8
•	Added assured by characterization table notes to output short-circuit current, output swing, and input bias current specifications	
•	Changed Source Current Vs Output Voltage V _{CC} =2.7V plot with Output Voltage vs Output Current (Claw) plot in Typical Characteristics section	10
•	Deleted plots Source Current Vs Output Voltage V_{CC} = 5V, Sinking Current vs Output Voltage V_{CC} =2.7V, Sinking Current vs Output Voltage V_{CC} =5V, Short-Circuit Current vs Temperature in <i>Typical Characteristics</i> section	10
•	Changed Open-Loop Output Impedance Vs Frequency plot in Typical Characteristics section	12
•	Added Receiving Notification and Support Resources sections to the Device and Documentation Support section	



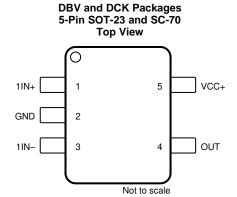
5 Pin Configuration and Functions





Pin Functions: LMV358

PIN		1/0	DECORIDATION		
NAME	NO.	1/0	DESCRIPTION		
1IN+	3	1	Noninverting input		
1IN-	2	1	Inverting input		
2IN+	5	1	Noninverting input		
2IN-	6	1	Inverting input		
2OUT	7	0	Output		
GND	4	_	Negative supply		
OUT	1	0	Output		
VCC+	8	_	Positive supply		



Pin Functions: LMV321

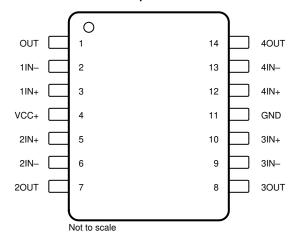
PIN		1/0	DESCRIPTION				
NAME	NO.	I/O	DESCRIPTION				
1IN+	1	I	Noninverting input				
1IN-	3	1	Inverting input				
GND	2	_	Negative supply				
OUT	4	0	Output				
VCC+	5		Positive supply				

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D and PW Packages 14-Pin SOIC and TSSOP Top View



Pin Functions: LMV324

PIN		I/O	DECODITION		
NAME	NO.	1/0	DESCRIPTION		
3/4 SHDN	_	I	Shutdown (logic low) / enable (logic high)		
1/2 SHDN	_	I	Shutdown (logic low) / enable (logic high)		
1IN+	3	I	Noninverting input		
1IN-	2	1	Inverting input		
2IN+	5	I	Noninverting input		
2IN-	6	I	Inverting input		
2OUT	7	0	Output		
3IN+	10	I	Noninverting input		
3IN-	9	I	Inverting input		
3OUT	8	0	Output		
4IN+	12	I	Noninverting input		
4IN-	13	I	Inverting input		
4OUT	14	0	Output		
GND	11	_	Negative supply		
OUT	1	0	OUT		
VCC+	4	_	Positive supply		

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6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) (1)

			MIN	MAX	UNIT
V _{CC}	Supply voltage ⁽²⁾			5.5	V
V_{ID}	Differential input voltage (3)		-5.5	5.5	V
VI	Input voltage (either input)	Input voltage (either input)		5.7	V
	Duration of output short circuit (one amplifier) to ground (4)	At or below $T_A = 25$ °C, $V_{CC} \le 5.5 \text{ V}$	ι	Jnlimited	
T_{J}	Operating virtual junction temperature			150	°C
T _{stg}	Storage temperature	·	-65	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- (2) All voltage values (except differential voltages and V_{CC} specified for the measurement of I_{OS}) are with respect to the network GND.
- (3) Differential voltages are at IN+ with respect to IN-.
- (4) Short circuits from outputs to V_{CC} can cause excessive heating and eventual destruction.

6.2 ESD Ratings

			VALUE	UNIT
V	Electrostatic	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	±2000	\/
V _(ESD)	discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101, all pins (2)	±1000	V

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions⁽¹⁾

			MIN	MAX	UNIT
V_{CC}	Supply voltage (single-supply operation)		2.7	5.5	V
_	Operating free air temperature	I temperature (LMV321, LMV358, LMV324, LMV321IDCK)	-40	125)
IA	Operating free-air temperature	Q temperature	-40	125	

All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. See Implications of Slow or Floating CMOS Inputs.

6.4 Thermal Information: LMV321

		LM\		
	THERMAL METRIC ⁽¹⁾		DCK (SC-70)	UNIT
		5 PINS	5 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	232.9	239.6	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

6.5 Thermal Information: LMV324

			LMV324			
	THERMAL METRIC (1)	D (SOIC)	PW (TSSOP)	UNIT		
		14 PINS	14 PINS			
$R_{\theta JA}$	Junction-to-ambient thermal resistance	102.1	148.3	°C/W		

 For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

Product Folder Links: LMV321 LMV324 LMV358

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



6.6 Thermal Information: LMV358

			LMV	358		
	THERMAL METRIC ⁽¹⁾	D (SOIC)	DGK (VSSOP)	DDU (VSSOP)	PW (TSSOP)	UNIT
		8 PINS	8 PINS	8 PINS	8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	207.9	201.2	210	200.7	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

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Product Folder Links: LMV321 LMV324 LMV358



6.7 Electrical Characteristics: V_{cc} + = 2.7 V

 $V_{CC+} = 2.7 \text{ V}, T_A = 25^{\circ}\text{C} \text{ (unless otherwise noted)}$

	PARAMETER	TEST CONDI	TIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
V _{IO}	Input offset voltage				1.7	7	mV
α_{VIO}	Average temperature coefficient of input offset voltage				5		μV/°C
I _{IB}	Input bias current				11	250	nA
I _{IO}	Input offset current				5	50	nA
CMRR	Common-mode rejection ratio	$V_{CM} = 0 \text{ to } 1.7 \text{ V}$		50	63		dB
k _{SVR}	Supply-voltage rejection ratio	$V_{CC} = 2.7 \text{ V to 5 V, V}_{O} =$	= 1 V	50	60		dB
\/	Common-mode input voltage	CMRR ≥ 50 dB	OMPR > 50 dR				V
V _{ICR}	range	CIVIRR 2 30 db			1.9	1.7	V
V	Output quing	D 10 k0 to 1 25 V	High level	V _{CC} - 100	V _{CC} - 10		mV
Vo	Output swing	$R_L = 10 \text{ k}\Omega \text{ to } 1.35 \text{ V}$	Low level		60	180	IIIV
		LMV321I			80	170	
I _{CC}	Supply current	LMV358I (both amplifier	s)		140	340	μΑ
		LMV324I (all four amplif	iers)		260	680	
B ₁	Unity-gain bandwidth	C _L = 200 pF			1		MHz
Φ_{m}	Phase margin				60		0
G _m	Gain margin				10		dB
V _n	Equivalent input noise voltage	f = 1 kHz			46		nV/√ Hz
In	Equivalent input noise current	f = 1 kHz			0.17		pA/√ Hz

⁽¹⁾ Typical values represent the likely parametric nominal values determined at the time of characterization. Typical values depend on the application and configuration and may vary over time. Typical values are not ensured on production material.



6.8 Electrical Characteristics: V_{CC} + = 5 V

 $V_{CC+} = 5 \text{ V}$, at specified free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
\ /	lance offers college	T _A = 25°C		1.7	7	\/
V_{IO}	Input offset voltage	$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$			9	mV
α_{VIO}	Average temperature coefficient of input offset voltage	T _A = 25°C		5		μV/°C
I _{IB}	Input bias current	$T_A = 25^{\circ}C$ $T_A = -40^{\circ}C \text{ to } +125^{\circ}C$		15	250 ⁽²⁾ 500 ⁽²⁾	nA
		T _A = -40 C to +123 C		5	50 ⁽²⁾	
I_{IO}	Input offset current	$T_A = 25 \text{ C}$ $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$		3	150 ⁽²⁾	nA
CMRR	Common-mode rejection	V _{CM} = 0 to 4 V	50	65	100	dB
OWNER	ratio	T _A = 25°C	30			ub ub
k _{SVR}	Supply-voltage rejection ratio	$V_{CC} = 2.7 \text{ V to 5 V, } V_{O} = 1 \text{ V, } V_{CM} = 1 \text{ V}$ $T_A = 25^{\circ}\text{C}$	50	60		dB
Vion	Common-mode input	CMRR ≥ 50 dB, T _A = 25°C	0	-0.2		V
V _{ICR}	voltage range	CIVILITY = 30 dB, 1 _A = 23 C		4.2	4	V
		$R_L = 2 \text{ k}\Omega$ to 2.5 V, high level, $T_A = 25^{\circ}\text{C}$	V _{CC} – 300	$V_{CC} - 40$		
		R_L = 2 k Ω to 2.5 V, high level, T_A = -40°C to +125°C	V _{CC} - 400 ⁽²⁾			
		T _A = 25°C, low level		120	300	
	Outside and and	$T_A = -40$ °C to +125°C, low level			400 ⁽²⁾	
Vo	Output swing	R_L = 10 k Ω to 2.5 V, high level, T_A = 25°C	V _{CC} - 100	V _{CC} - 10		mV
		R_L = 10 k Ω to 2.5 V, high level, T_A = -40°C to +125°C	V _{CC} - 200 ⁽²⁾			
		T _A = 25°C, low level		65	180	
		$T_A = -40$ °C to +125°C, low level			280(2)	
	Large-signal differential	$R_L = 2 \text{ k}\Omega$, $T_A = 25^{\circ}\text{C}$	15	100		
A_{VD}	voltage gain	$R_L = 2 \text{ k}\Omega, T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$	10 ⁽²⁾			V/mV
	Output short-circuit	Sourcing, V _O = 0 V, T _A = 25°C	5 ⁽²⁾	40		^
los	current	Sinking, V _O = 5 V, T _A = 25°C	10 ⁽²⁾	40		mA
		LMV321I, T _A = 25°C		130	250	
		LMV321I, T _A = -40°C to +125°C			350	
		LMV358I (both amplifiers), T _A = 25°C		210	440	
I_{CC}	Supply current	LMV358I (both amplifiers), T _A = -40°C to +125°C			615	μА
		LMV324I (all four amplifiers), T _A = 25°C		410	830	
		LMV324I (all four amplifiers), T _A = -40°C to +125°C			1160	
B ₁	Unity-gain bandwidth	C _L = 200 pF, T _A = 25°C		1		MHz
Φ_{m}	Phase margin	T _A = 25°C		60		0
G _m	Gain margin	T _A = 25°C		10		dB
V _n	Equivalent input noise voltage	f = 1 kHz, T _A = 25°C		39		nV/√ Hz
In	Equivalent input noise current	f = 1 kHz, T _A = 25°C		0.21		pA/√ Hz
SR	Slew rate	T _A = 25°C		1		V/μs

⁽¹⁾ Typical values represent the likely parametric nominal values determined at the time of characterization. Typical values depend on the application and configuration and may vary over time. Typical values are not ensured on production material.

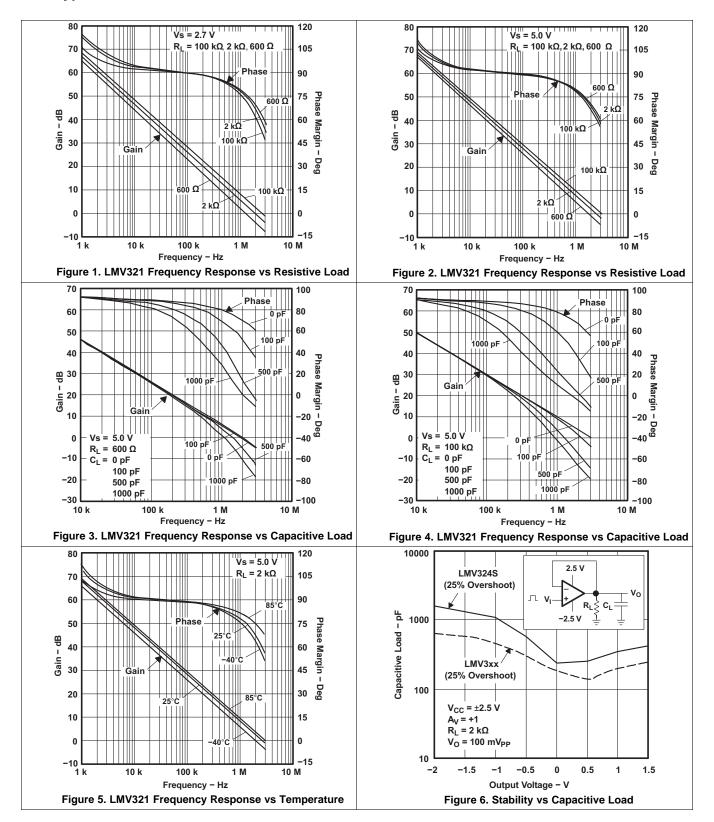
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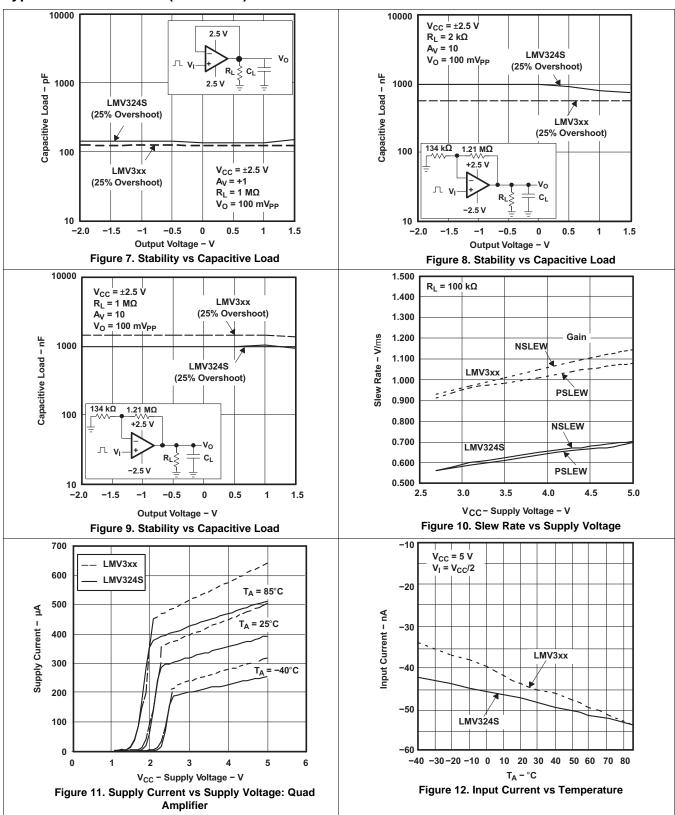
⁽²⁾ Assured by characterization. Not production tested.



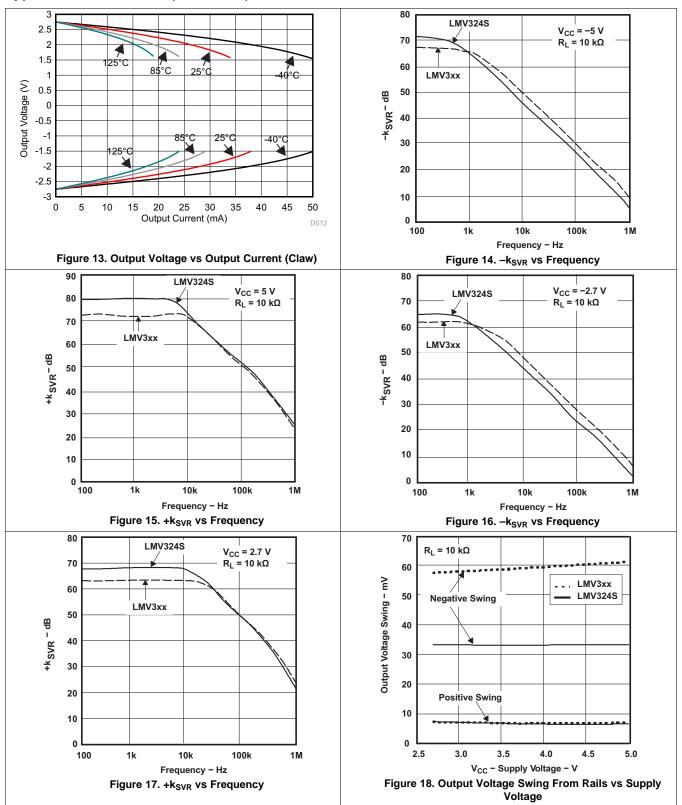
6.9 Typical Characteristics



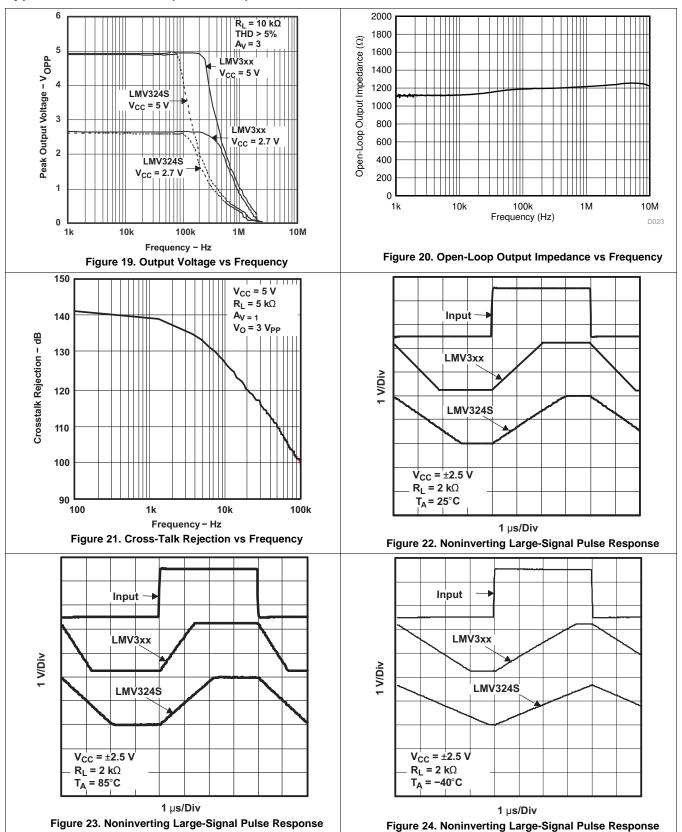




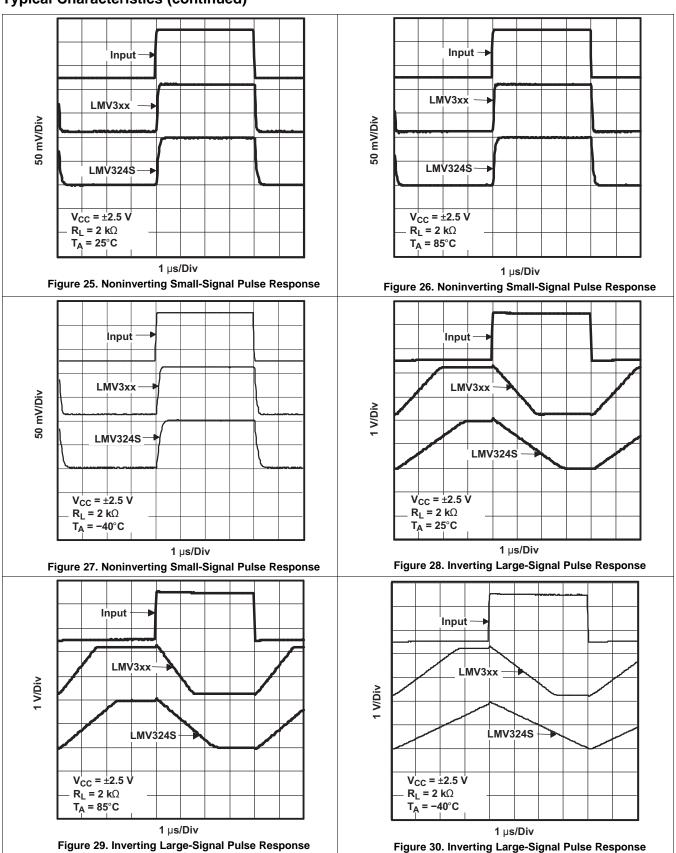




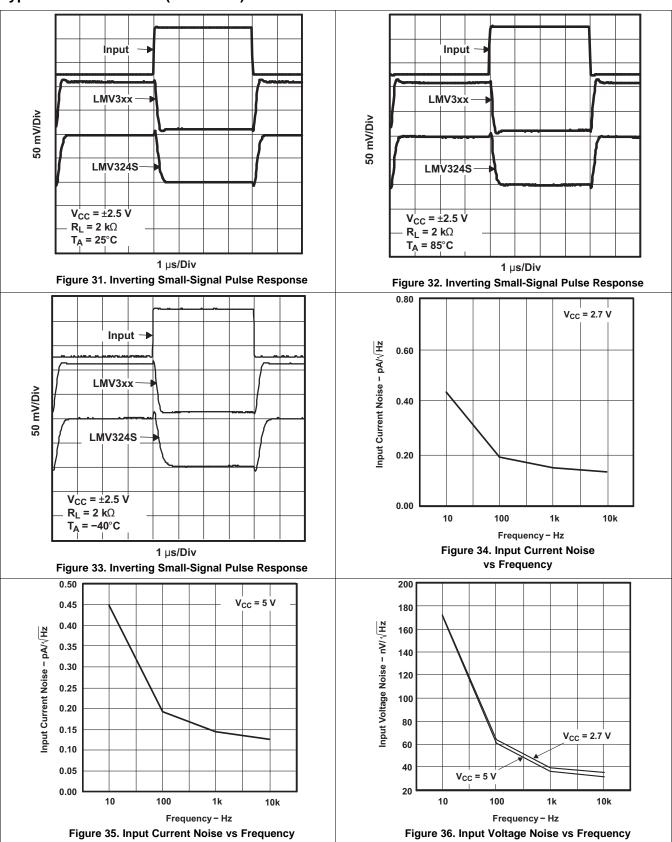




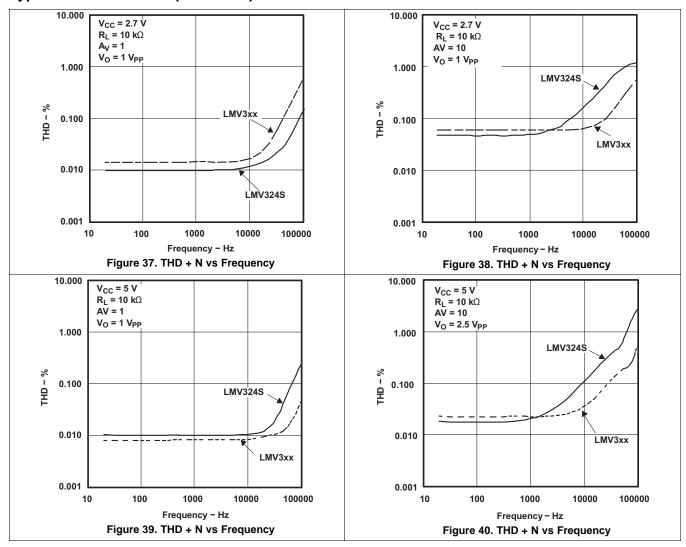




TEXAS INSTRUMENTS









7 Detailed Description

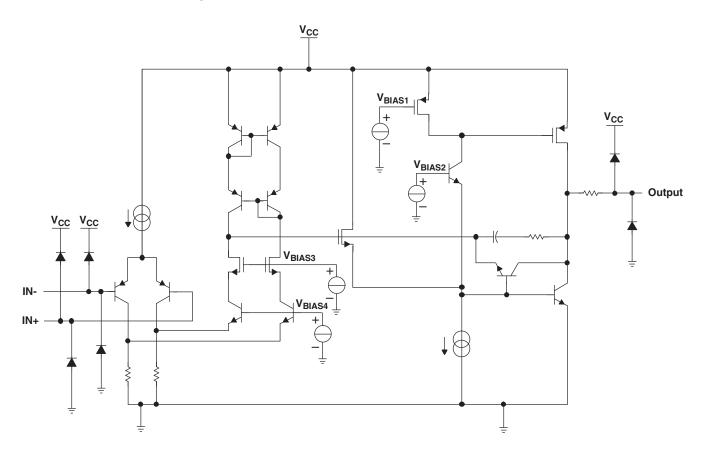
7.1 Overview

The LMV321, LMV358, and LMV324 devices are single, dual, and quad low-voltage (2.7 V to 5.5 V) operational amplifiers with rail-to-rail output swing.

The LMV321, LMV358, and LMV324 devices are the most cost-effective solutions for applications where low-voltage operation, space saving, and low cost are needed. These amplifiers are designed specifically for low-voltage (2.7 V to 5 V) operation, with performance specifications meeting or exceeding the LM358 and LM324 devices that operate from 5 V to 30 V. Additional features of the LMV3xx devices are a common-mode input voltage range that includes ground, 1-MHz unity-gain bandwidth, and 1-V/ μ s slew rate.

The LMV321 device is available in the ultra-small package, which is approximately one-half the size of the DBV (SOT-23) package. This package saves space on printed circuit boards and enables the design of small portable electronic devices. It also allows the designer to place the device closer to the signal source to reduce noise pickup and increase signal integrity.

7.2 Functional Block Diagram



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7.3 Feature Description

7.3.1 Operating Voltage

The LMV321, LMV358, LMV324 devices are fully specified and ensured for operation from 2.7 V to 5 V. In addition, many specifications apply from –40°C to 125°C. Parameters that vary significantly with operating voltages or temperature are shown in the *Typical Characteristics* graphs.

7.3.2 Unity-Gain Bandwidth

The unity-gain bandwidth is the frequency up to which an amplifier with a unity gain may be operated without greatly distorting the signal. The LMV321, LMV358, LMV324 devices have a 1-MHz unity-gain bandwidth.

7.3.3 Slew Rate

The slew rate is the rate at which an operational amplifier can change its output when there is a change on the input. The LMV321, LMV358, LMV324 devices have a 1-V/μs slew rate.

7.4 Device Functional Modes

The LMV321, LMV358, LMV324 devices are powered on when the supply is connected. Each of these devices can be operated as a single supply operational amplifier or dual supply amplifier depending on the application.

Product Folder Links: LMV321 LMV324 LMV358



8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Typical Application

Some applications require differential signals. Figure 41 shows a simple circuit to convert a single-ended input of 0.5 to 2 V into differential output of ± 1.5 V on a single 2.7-V supply. The output range is intentionally limited to maximize linearity. The circuit is composed of two amplifiers. One amplifier acts as a buffer and creates a voltage, V_{OUT+} . The second amplifier inverts the input and adds a reference voltage to generate V_{OUT-} . Both V_{OUT+} and V_{OUT-} range from 0.5 to 2 V. The difference, V_{DIFF} , is the difference between V_{OUT+} and V_{OUT-} . The LMV358 was used to build this circuit.

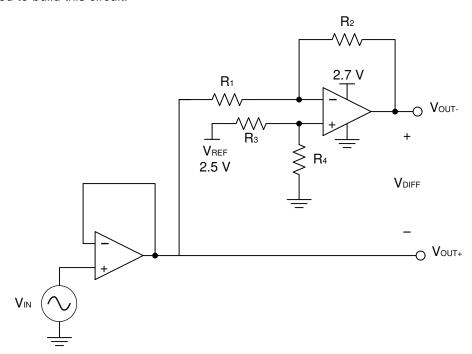


Figure 41. Schematic for Single-Ended Input to Differential Output Conversion



Typical Application (continued)

8.1.1 Design Requirements

The design requirements are as follows:

Supply voltage: 2.7 V Reference voltage: 2.5 V

Input: 0.5 to 2 V

Output differential: ±1.5 V

8.1.2 Detailed Design Procedure

The circuit in Figure 41 takes a single-ended input signal, V_{IN}, and generates two output signals, V_{OUT+} and V_{OUT-} using two amplifiers and a reference voltage, V_{REF} . V_{OUT+} is the output of the first amplifier and is a buffered version of the input signal, V_{IN} (see Equation 1). V_{OUT-} is the output of the second amplifier which uses V_{REF} to add an offset voltage to V_{IN} and feedback to add inverting gain. The transfer function for V_{OUT} is Equation 2.

$$V_{OUT+} = V_{IN} \tag{1}$$

$$V_{\text{OUT-}} = V_{\text{REF}} \times \left(\frac{R_4}{R_3 + R_4}\right) \times \left(1 + \frac{R_2}{R_1}\right) - V_{\text{IN}} \times \frac{R_2}{R_1}$$
(2)

The differential output signal, V_{DIFF}, is the difference between the two single-ended output signals, V_{OUT+} and V_{OUT-} . Equation 3 shows the transfer function for V_{DIFF} . By applying the conditions that $R_1 = R_2$ and $R_3 = R_4$, the transfer function is simplified into Equation 6. Using this configuration, the maximum input signal is equal to the reference voltage and the maximum output of each amplifier is equal to the V_{REF}. The differential output range is 2xV_{REF}. Furthermore, the common mode voltage will be one half of V_{REF} (see Equation 7).

$$V_{DIFF} = V_{OUT+} - V_{OUT-} = V_{IN} \times \left(1 + \frac{R_2}{R_1}\right) - V_{REF} \times \left(\frac{R_4}{R_3 + R_4}\right) \left(1 + \frac{R_2}{R_1}\right)$$
(3)

$$V_{OUT+} = V_{IN} \tag{4}$$

$$V_{OUT-} = V_{REF} - V_{IN}$$
 (5)

$$V_{DIFF} = 2xV_{IN} - V_{REF}$$
 (6)

$$V_{cm} = \left(\frac{V_{OUT+} + V_{OUT-}}{2}\right) = \frac{1}{2}V_{REF}$$
(7)

8.1.2.1 Amplifier Selection

Linearity over the input range is key for good dc accuracy. The common mode input range and the output swing limitations determine the linearity. In general, an amplifier with rail-to-rail input and output swing is required. Bandwidth is a key concern for this design. Because LMV358 has a bandwidth of 1 MHz, this circuit will only be able to process signals with frequencies of less than 1 MHz.

8.1.2.2 Passive Component Selection

Because the transfer function of V_{OUT} is heavily reliant on resistors (R₁, R₂, R₃, and R₄), use resistors with low tolerances to maximize performance and minimize error. This design used resistors with resistance values of 36 k Ω with tolerances measured to be within 2%. If the noise of the system is a key parameter, the user can select smaller resistance values (6 k Ω or lower) to keep the overall system noise low. This ensures that the noise from the resistors is lower than the amplifier noise.

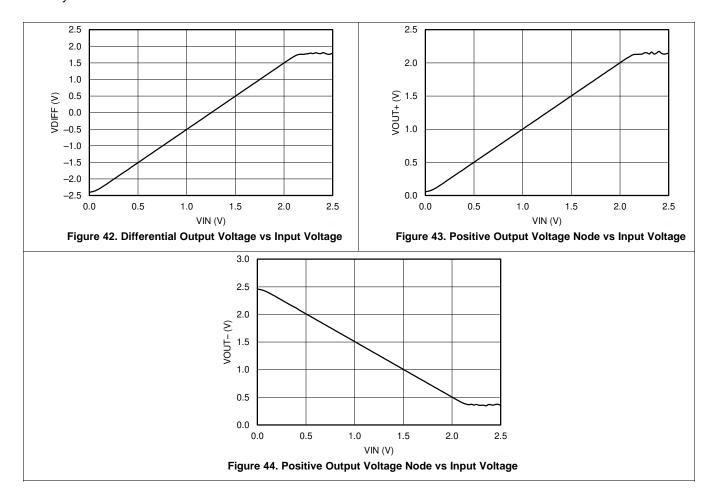
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Typical Application (continued)

8.1.3 Application Curves

The measured transfer functions in Figure 42, Figure 43, and Figure 44 were generated by sweeping the input voltage from 0 V to 2.5 V. However, this design should only be used between 0.5 V and 2 V for optimum linearity.





9 Power Supply Recommendations

The LMV321, LMV358, LMV324 devices are specified for operation from 2.7 to 5 V; many specifications apply from –40°C to 125°C. The *Typical Characteristics* section presents parameters that can exhibit significant variance with regard to operating voltage or temperature.

CAUTION

Supply voltages larger than 5.5 V can permanently damage the device (see the *Absolute Maximum Ratings*).

Place 0.1-μF bypass capacitors close to the power-supply pins to reduce errors coupling in from noisy or high impedance power supplies. For more detailed information on bypass capacitor placement, refer to the *Layout*.

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10 Layout

10.1 Layout Guidelines

For best operational performance of the device, use good PCB layout practices, including:

- Noise can propagate into analog circuitry through the power pins of the circuit as a whole, as well as the
 operational amplifier. Bypass capacitors are used to reduce the coupled noise by providing low impedance
 power sources local to the analog circuitry.
 - Connect low-ESR, 0.1-μF ceramic bypass capacitors between each supply pin and ground, placed as close to the device as possible. A single bypass capacitor from V+ to ground is applicable for single supply applications.
- Separate grounding for analog and digital portions of circuitry is one of the simplest and most-effective methods of noise suppression. One or more layers on multilayer PCBs are usually devoted to ground planes. A ground plane helps distribute heat and reduces EMI noise pickup. Make sure to physically separate digital and analog grounds, paying attention to the flow of the ground current.
- To reduce parasitic coupling, run the input traces as far away from the supply or output traces as possible. If
 it is not possible to keep them separate, it is much better to cross the sensitive trace perpendicular as
 opposed to in parallel with the noisy trace.
- Place the external components as close to the device as possible. Keeping RF and RG close to the inverting input minimizes parasitic capacitance, as shown in *Layout Example*.
- Keep the length of input traces as short as possible. Always remember that the input traces are the most sensitive part of the circuit.
- Consider a driven, low-impedance guard ring around the critical traces. A guard ring can significantly reduce leakage currents from nearby traces that are at different potentials.

10.2 Layout Example

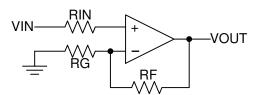


Figure 45. Operational Amplifier Schematic for Noninverting Configuration

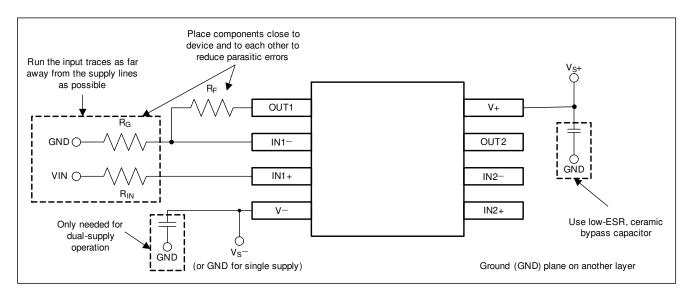


Figure 46. Operational Amplifier Board Layout for Noninverting Configuration

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11 Device and Documentation Support

11.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 1. Related Links

PARTS	PRODUCT FOLDER	ORDER NOW	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
LMV321	Click here	Click here	Click here	Click here	Click here
LMV358	Click here	Click here	Click here	Click here	Click here
LMV324	Click here	Click here	Click here	Click here	Click here

11.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

11.3 Support Resources

TI E2ETM support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

11.4 Trademarks

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

11.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

11.6 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

Product Folder Links: LMV321 LMV324 LMV358



12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser based versions of this data sheet, refer to the left hand navigation.

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Product Folder Links: LMV321 LMV324 LMV358



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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
LMV321IDBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(RC1F, RC1K)	Samples
LMV321IDBVRE4	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(RC1F, RC1K)	Samples
LMV321IDBVRG4	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(RC1F, RC1K)	Samples
LMV321IDBVT	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(RC1F, RC1K)	Samples
LMV321IDBVTE4	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(RC1F, RC1K)	Samples
LMV321IDCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU SN NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	(R3F, R3K, R3O, R3 R, R3Z)	Samples
LMV321IDCKRG4	ACTIVE	SC70	DCK	5	3000	RoHS & Green	SN	Level-2-260C-1 YEAR	-40 to 125	(R3F, R3K, R3O, R3 R, R3Z)	Samples
LMV321IDCKT	ACTIVE	SC70	DCK	5	250	RoHS & Green	NIPDAU SN NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	(R3C, R3F, R3R)	Samples
LMV324ID	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LMV324I	Samples
LMV324IDR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	LMV324I	Samples
LMV324IDRE4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LMV324I	Samples
LMV324IDRG4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LMV324I	Samples
LMV324IPWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	MV324I	Samples
LMV324IPWRE4	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	MV324I	Samples
LMV324IPWRG4	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	MV324I	Samples
LMV324QD	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LMV324Q	Samples
LMV324QDG4	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LMV324Q	Samples
LMV324QDR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LMV324Q	Samples
LMV324QDRG4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LMV324Q	Samples





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Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
LMV324QPW	ACTIVE	TSSOP	PW	14	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	MV324Q	Samples
LMV324QPWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU SN	Level-2-260C-1 YEAR	-40 to 125	MV324Q	Samples
LMV324QPWRE4	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	SN	Level-2-260C-1 YEAR	-40 to 125	MV324Q	Samples
LMV358ID	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	MV358I	Samples
LMV358IDDUR	ACTIVE	VSSOP	DDU	8	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	RA5R	Samples
LMV358IDDURG4	ACTIVE	VSSOP	DDU	8	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	RA5R	Samples
LMV358IDG4	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	MV358I	Samples
LMV358IDGKR	ACTIVE	VSSOP	DGK	8	2500	RoHS & Green	NIPDAU NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	(R5B, R5Q, R5R)	Samples
LMV358IDGKRG4	ACTIVE	VSSOP	DGK	8	2500	RoHS & Green	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	(R5B, R5Q, R5R)	Samples
LMV358IDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	MV358I	Samples
LMV358IDRE4	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	MV358I	Samples
LMV358IDRG4	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	MV358I	Samples
LMV358IPW	ACTIVE	TSSOP	PW	8	150	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	MV358I	Samples
LMV358IPWG4	ACTIVE	TSSOP	PW	8	150	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	MV358I	Samples
LMV358IPWR	ACTIVE	TSSOP	PW	8	2000	RoHS & Green	NIPDAU SN	Level-2-260C-1 YEAR	-40 to 125	MV358I	Samples
LMV358IPWRE4	ACTIVE	TSSOP	PW	8	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	MV358I	Samples
LMV358IPWRG4	ACTIVE	TSSOP	PW	8	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	MV358I	Samples
LMV358QD	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	MV358Q	Samples
LMV358QDDUR	ACTIVE	VSSOP	DDU	8	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	RAHR	Samples
LMV358QDDURG4	ACTIVE	VSSOP	DDU	8	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	RAHR	Samples
LMV358QDG4	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	MV358Q	Samples

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Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
LMV358QDGKR	ACTIVE	VSSOP	DGK	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(RHO, RHR)	Samples
LMV358QDGKRG4	ACTIVE	VSSOP	DGK	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(RHO, RHR)	Samples
LMV358QDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	MV358Q	Samples
LMV358QPWR	ACTIVE	TSSOP	PW	8	2000	RoHS & Green	NIPDAU SN	Level-2-260C-1 YEAR	-40 to 125	MV358Q	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.



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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



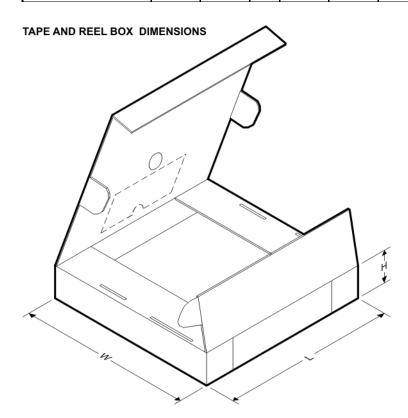
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMV321IDBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
LMV321IDBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV321IDBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV321IDBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
LMV321IDCKR	SC70	DCK	5	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
LMV321IDCKR	SC70	DCK	5	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
LMV321IDCKT	SC70	DCK	5	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
LMV321IDCKT	SC70	DCK	5	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
LMV324IDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
LMV324IDR	SOIC	D	14	2500	330.0	16.8	6.5	9.5	2.1	8.0	16.0	Q1
LMV324IDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
LMV324IDRG4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
LMV324IDRG4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
LMV324IPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
LMV324IPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
LMV324IPWRG4	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
LMV324QDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
LMV324QPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1



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Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMV324QPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
LMV358IDDUR	VSSOP	DDU	8	3000	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3
LMV358IDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LMV358IDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LMV358IDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.3	1.3	8.0	12.0	Q1
LMV358IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LMV358IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LMV358IDR	SOIC	D	8	2500	330.0	12.8	6.4	5.2	2.1	8.0	12.0	Q1
LMV358IDRG4	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LMV358IPWR	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
LMV358IPWRG4	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
LMV358QDDUR	VSSOP	DDU	8	3000	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3
LMV358QDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LMV358QDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.3	1.3	8.0	12.0	Q1
LMV358QDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LMV358QPWR	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMV321IDBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0



PACKAGE MATERIALS INFORMATION

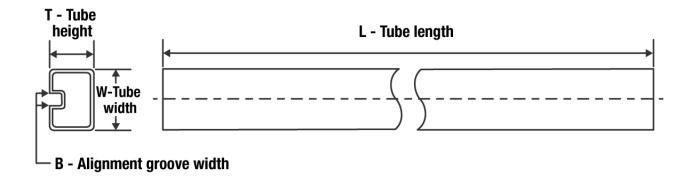
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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMV321IDBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
LMV321IDBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
LMV321IDBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
LMV321IDCKR	SC70	DCK	5	3000	180.0	180.0	18.0
LMV321IDCKR	SC70	DCK	5	3000	190.0	190.0	30.0
LMV321IDCKT	SC70	DCK	5	250	190.0	190.0	30.0
LMV321IDCKT	SC70	DCK	5	250	180.0	180.0	18.0
LMV324IDR	SOIC	D	14	2500	340.5	336.1	32.0
LMV324IDR	SOIC	D	14	2500	364.0	364.0	27.0
LMV324IDR	SOIC	D	14	2500	853.0	449.0	35.0
LMV324IDRG4	SOIC	D	14	2500	853.0	449.0	35.0
LMV324IDRG4	SOIC	D	14	2500	340.5	336.1	32.0
LMV324IPWR	TSSOP	PW	14	2000	853.0	449.0	35.0
LMV324IPWR	TSSOP	PW	14	2000	364.0	364.0	27.0
LMV324IPWRG4	TSSOP	PW	14	2000	853.0	449.0	35.0
LMV324QDR	SOIC	D	14	2500	853.0	449.0	35.0
LMV324QPWR	TSSOP	PW	14	2000	366.0	364.0	50.0
LMV324QPWR	TSSOP	PW	14	2000	853.0	449.0	35.0
LMV358IDDUR	VSSOP	DDU	8	3000	202.0	201.0	28.0
LMV358IDGKR	VSSOP	DGK	8	2500	366.0	364.0	50.0
LMV358IDGKR	VSSOP	DGK	8	2500	358.0	335.0	35.0
LMV358IDGKR	VSSOP	DGK	8	2500	370.0	355.0	55.0
LMV358IDR	SOIC	D	8	2500	853.0	449.0	35.0
LMV358IDR	SOIC	D	8	2500	340.5	336.1	25.0
LMV358IDR	SOIC	D	8	2500	364.0	364.0	27.0
LMV358IDRG4	SOIC	D	8	2500	340.5	336.1	25.0
LMV358IPWR	TSSOP	PW	8	2000	366.0	364.0	50.0
LMV358IPWRG4	TSSOP	PW	8	2000	853.0	449.0	35.0
LMV358QDDUR	VSSOP	DDU	8	3000	202.0	201.0	28.0
LMV358QDGKR	VSSOP	DGK	8	2500	358.0	335.0	35.0
LMV358QDGKR	VSSOP	DGK	8	2500	370.0	355.0	55.0
LMV358QDR	SOIC	D	8	2500	340.5	336.1	25.0
LMV358QPWR	TSSOP	PW	8	2000	366.0	364.0	50.0



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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
LMV324ID	D	SOIC	14	50	506.6	8	3940	4.32
LMV324QD	D	SOIC	14	50	506.6	8	3940	4.32
LMV324QDG4	D	SOIC	14	50	506.6	8	3940	4.32
LMV324QPW	PW	TSSOP	14	90	530	10.2	3600	3.5
LMV358ID	D	SOIC	8	75	506.6	8	3940	4.32
LMV358ID	D	SOIC	8	75	507	8	3940	4.32
LMV358IDG4	D	SOIC	8	75	507	8	3940	4.32
LMV358IDG4	D	SOIC	8	75	506.6	8	3940	4.32
LMV358IPW	PW	TSSOP	8	150	530	10.2	3600	3.5
LMV358IPWG4	PW	TSSOP	8	150	530	10.2	3600	3.5
LMV358QD	D	SOIC	8	75	507	8	3940	4.32
LMV358QDG4	D	SOIC	8	75	507	8	3940	4.32

D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





SMALL OUTLINE INTEGRATED CIRCUIT



- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- E. Falls within JEDEC MO-187 variation AA, except interlead flash.



DGK (S-PDSO-G8)

PLASTIC SMALL OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





SMALL OUTLINE PACKAGE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153, variation AA.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



DCK (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Falls within JEDEC MO-203 variation AA.



DCK (R-PDSO-G5)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



DDU (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE

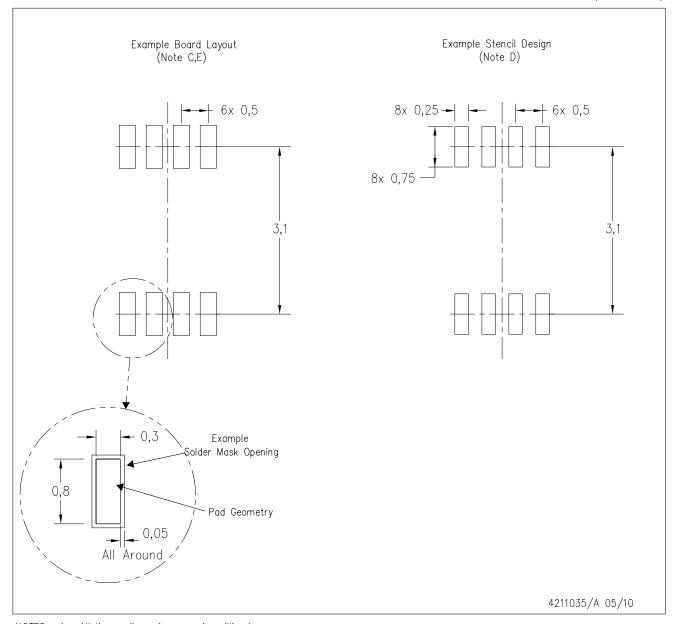


- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion.
- D. Falls within JEDEC MO-187 variation CA.



DDU (S-PDSO-G8)

PLASTIC SMALL OUTLINE PACKAGE (DIE UP)



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





SMALL OUTLINE TRANSISTOR



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.
 3. Reference JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.



SMALL OUTLINE TRANSISTOR



- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR





^{7.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

^{8.} Board assembly site may have different recommendations for stencil design.

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